

Compact picosecond lasers for OEM and series production



About Us

Profile



Manufacturer of compact, DPSS lasers for scientific and industrial applications. Our aim is to bring cost effective lasers to medical and industrial OEM markets



Accumulated experience in laser development, production and service over 35 years.



Advanced short pulse generation technology



Designing and adopting lasers to OEM for integrators



Series production



Employees – team of 25 professional persons



Founded in April 2018

Field of expertise



Diode pumped Nd:YAG, Nd:YLF, Nd:YVO, Nd:YAP lasers + harmonic generators



Short pulse generation (20 -50ps, 250-500 ps, <3 ns)



Pulse energy (1µJ - 2 mJ)



Repetition rate (single shot to 10 kHz)



Custom laser systems for specific applications

Applications of our lasers

- Seeder for amplifiers in the medical field
- Medical diagnostic systems
- OLED repair

- LIDAR
- Digital holography
- Laser Induced Breakdown Spectroscopy
- Non-linear spectroscopy
- Remote sensing
- Matrix Assisted Laser Desorption/Ionization (MALDI)



The First Picosecond Mini Lasers in the Market!

NEW

Gain-Switched **1064 nm** Picosecond Mini Laser **ANGIS** Diode Pumped Sub-Nanosecond Passively or Actively Q-Switched **880 nm** Mini Laser **AGRIUS**

FEATURES

- 1 µJ pulse energy (>100 µJ after the First Amplification Stage)
- Short pulse duration < 50 ps (<20 ps available)
- No Semiconductor Modulator (SESAM), no Mode Locking
- > Repetition Rate up to 10 kHz
- > Ultra-compact
- Passively or Actively Q-switched 880 nm Pump Laser
- Single 808 nm Pump Source for 880 nm Pump Laser and for 1064 nm Preamplifier
- > Series Production

FEATURES

- > True Three Level Nd dopped Laser
- > 10 µJ pulse energy at 880 nm
- Short pulse duration < 1 ns (Passively QS) and < 0.5 ns Actively QS)
- > Repetition Rate up to 10 kHz
- > Ultra-compact
- > Second Harmonics 440 nm
- > Series Production



Diode Pumped Picosecond Passively Q-Switched Laser MPL2210

NEW

FEATURES

- > More than **2 mJ** pulse energy at **1064 nm**
- Short pulse duration < 250-270 ps</p>
- > 1 100 Hz repetition rate
- > Ultra-compact
- > Passively Q-switched
- > Average power 200 mW
- > High peak power > 7 MW
- > Guaranteed > 3 Gshot lifetime
- Other wavelengths (e.g. 532 nm, 355 nm, 266 nm) are available

MPL2210 series DPSS passively Q-switched picosecond laser deliver high peak powers > 7 MW at 100 Hz repetition rate. Short laser cavity is fixed on thermo- stabilized and controlled baseplate which gives extremely stable output parameters performance. Small footprint is welcome point for integration into OEM lasers. Sub- nanosecond pulse duration of < 250-270 ps, high pulse energy more than 2 mJ, variable repetition rate from 1 Hz to 100 Hz covers many applications like pollution monitoring, DNA analysis, supercontinuum generation and many others.

Due to short pulse duration and high pulse energy laser delivers high peak power which is up to 7 MW. Optional conversion to green (532 nm) and ultraviolet (355 nm, 266 nm) is also available.

APPLICATIONS

- Laser-induced breakdown spectroscopy (LIBS)
- > Time resolved fluorescence measurements
- > DNA analysis
- > Pollution monitoring
- > Remote sensing
- > Supercontinuum generation
- > Ignition of gas mixtures







Specifications ¹⁾

MODEL	MPL2210	
Pulse energy		
at 1064 nm	2 mJ	
at 532 nm	1 mJ	
at 355 nm	0.5 mJ	
at 266 nm	0.25 mJ	
Typical pulse duration	< 250 ps - 270 ps ²)	
Pulse to pulse energy stabilit	ry (RMS)	
at 1064 nm	< 1.0 % ³⁾	
at 532 nm	< 2.0 % ³⁾	
at 355 nm	< 3.0 % ³⁾	
at 266 nm	< 4.0 % ³⁾	
Power drift	± 3.0 % ⁴⁾	
Pulse repetition rate ⁵⁾	1 – 100 Hz	
Beam profile	close to Gaussian	
Beam divergence 6)	< 6 mrad	
Polarization	linear, horizontal at 1064 nm	
Spectral linewidth	SLM	
Beam pointing stability 7)	< 10 µrad	
Typical beam diameter ⁸⁾	1.5 mm	
Optical jitter	~ 2 µs RMS ⁹⁾	
DIMENSIONS		
	125 x 295 x 76 mm (with harmonics)	

Least based (Wyd ydd)	125 × 295 × 76 mm (with harmonics)
	99 × 174 × 45.5 mm (OEM version)
Controllar unit (Wyl y L)	257 × 271 × 153 mm
	75 × 200 × 70 mm (OEM version)

OPERATING REQUIREMENTS

TEC	
20 – 25 °C	
10 - 80 % (non-condensing)	
100 – 230 VAC, single phase, 50 – 60 Hz ¹⁰⁾	
< 20 W	

- ¹⁾ Due to continuous improvements all specifications are subject to change. Unless stated otherwise all specifications are measured at 1064 nm.
- FWHM level at 1064 nm.
 Averaged from 60 seconds time
- interval in 5 series.
 Over 8-hour period after max 5 minutes of warm-up when ambient temperature variation is less than ±2 °C.
- Factory-set pulse repetition rate is fixed at 10 Hz repetition rate. Higher repetition rates are available, please inquire for more details.
- Full angle measured at the 1/e² level. Lower beam divergence is available upon request, please inquire for more details.
- 7) RMS value measured from 1000 shots.
- ⁸⁾ Beam diameter is measured 20 cm from laser output at the 1/e² level.
- ⁹⁾ In respect to Q-switch triggering rising edge pulse.
- ¹⁰⁾ Laser can be powered from appropriate 12 VDC power source. Inquire for details.





Typical beam intensity profile (20 cm from laser output) of MPL2210 series lasers



MPL2210 series laser head dimensions OEM version (in mm)



MPL2210 series laser head dimensions (in mm)

Diode Pumped Picosecond Passively Q-Switched Lasers MPL2310 / MPL2510

FEATURES

- > More than 2 mJ pulse energy at 1064 nm
- > Short pulse duration < 500 ps
- > 1 100 Hz repetition rate
- Ultra-compact
- Passively Q-switched
- > Average power 200 mW
- > High peak power > 4 MW
- > Guaranteed > 3 Gshot lifetime
- Other wavelengths (e.g. 532 nm, 355 nm, 266 nm) are available

MPL2310 series DPSS passively Q-switched picosecond lasers deliver high peak powers > 5 MW at 100 Hz repetition rate. Short laser cavity is fixed on thermostabilized and controlled baseplate which gives extremely stable output parameters performance. Small footprint is welcome point for integration into OEM lasers. Subnanosecond pulse duration of < 350 ps, high pulse energy more than 2 mJ, variable repetition rate from 1 Hz to 100 Hz covers many applications like pollution monitoring, DNA analysis, supercontinuum generation and many others.

Due to short pulse duration and high pulse energy laser delivers high peak power which is up to 5 MW. Optional conversion to green (532 nm) and ultraviolet (355 nm, 266 nm) is also available.

APPLICATIONS

- Laser-induced breakdown spectroscopy (LIBS)
- Time resolved fluorescence measurements
- > DNA analysis
- > Pollution monitoring
- > Remote sensing
- > Supercontinuum generation
- > Ignition of gas mixtures







Specifications ¹⁾

MODEL	MPL2310 / MPL2510	MPL1310 / MPL1510	
Pulse energy			
at 1064 nm	2 mJ	1 mJ	
at 532 nm	1 mJ	0.5 mJ	
at 355 nm	0.5 mJ 0.25 mJ		
at 266 nm	0.25 mJ 0.15 mJ		
Typical pulse duration	<350 ps/ <500 ps ²⁾		
Pulse to pulse energy stability	y (RMS)		
at 1064 nm	< 1.() % ³⁾	
at 532 nm	< 2.0 % ³⁾		
at 355 nm	< 3.0 % ³⁾		
at 266 nm	< 4.0 % ³⁾		
Power drift	± 3.0 % ⁴⁾		
Pulse repetition rate 5)	1 – 100 Hz		
Beam profile	close to Gaussian		
Beam divergence 6)	< 6 mrad		
Polarization	linear, horizontal at 1064 nm		
Spectral linewidth	SLM		
Beam pointing stability 7)	< 10 µrad		
Typical beam diameter ⁸⁾	1.5 mm		
Optical jitter	~ 2 µs RMS ⁹		
DIMENSIONS			
	125 × 295 × 76 mm (with harmonics)		
	99 × 174 × 45.5 mm (OEM version)		
Controllor unit (Wyl y4)	257 × 271 × 153 mm		
Controller unit (W×L×H)	75 × 200 × 70 mm (OEM version)		

OPERATING REQUIREMENTS

air cooled		
15 – 30 °C		
10 - 80 % (non-condensing)		
100 – 230 VAC, single phase, 50 – 60 Hz ¹⁰⁾		
< 20 W	< 10 W	
	air co 15 - 10 - 80 % (no 100 - 230 VAC, single < 20 W	



- ²⁾ FWHM level at 1064 nm. Averaged from 60 seconds time interval in 5 series.
- ³⁾ Over 8-hour period after max 5 minutes of warm-up when ambient temperature variation is less than ±2 °C.
- Factory-set pulse repetition rate is fixed at 100 Hz repetition rate. Higher repetition rates are available, please inquire for more details.
- ⁵⁾ Full angle measured at the 1/e² level. Lower beam divergence is available upon request, please inquire for more details.
- ⁶⁾ RMS value measured from 1000 shots.
- ⁷⁾ Beam diameter is measured 20 cm from laser output at the 1/e² level.
- ⁸⁾ In respect to Q-switch triggering rising edge pulse.

⁹⁾ Laser can be powered from appropriate 12 VDC power source. Inquire for details.





Typical beam intensity profile (20 cm from laser output) of MPL2310 series lasers



MPL2310 series laser head dimensions OEM version (in mm)



MPL2310 series laser head dimensions (in mm)

Diode Pumped Sub-Nanosecond Actively Q-Switched Laser MPL15100

FEATURES

- > More than 0.5 mJ pulse energy at 1064 nm
- Short pulse duration < 700 ps</p>
- > Up to 1 kHz repetition rate
- 532 nm, 355 nm, 266 nm wavelengths as standard option
- > Actively Q-Switched
- > Peak Power 0.7 MW
- Other wavelengths (e.g. 532 nm, 355 nm, 266 nm) are available

MPL15100 series robust DPSS actively Q-switched sub-nanosecond lasers deliver multi-kW peak powers, less than 1 ns pulse duration at 1 kHz repetition rate. Short innovative laser cavity with is fixed on thermostabilized baseplate which gives extremely stable output parameters performance. Small footprint is welcome point for integration into OEM lasers. Sub-nanosecond pulse duration of < 700 ps with near transform limited spectral linewidth at repetition rates up to 1 kHz with low timing jitter of < 200 ps and energies more than 500 µJ covers broad spectrum of applications starting from LIBS, laser induced fluorescence to many others. Standard optional harmonics generator to green (532 nm) and ultraviolet (355 nm, 266 nm) is also available.

APPLICATIONS

- > Spectroscopy
- Marking
- > MALDI
- > Seeding laser amplifiers
- > Pollution Monitoring
- Remote sensing



Stand alone with harmonics

QS LASERS

Specifications 1)

MODEL	MPL15100	MPL15100-1K	
Pulse energy:			
at 1064 nm	0.5 mJ		
at 532 nm	0.25 mJ		
at 355 nm	0.15 mJ		
at 266 nm	0.1 mJ		
Typical pulse duration	< 700 ps ²⁾		
Pulse to pulse energy stability	y (RMS):		
at 1064 nm	< 0.5 % ³⁾		
at 532 nm	< 1.0 % ³⁾		
at 355 nm	< 1.5 % ³⁾		
at 266 nm	< 2.0 % ³⁾		
Power drift	± 3.0 % ⁴⁾		
Pulse repetition rate 5)	100 Hz 1 kHz		
Beam spatial profile	Close to Gaussian		
Beam divergence 6)	< 4 mrad		
Polarization	Linear, horizontal at 1064 nm		
Spectral linewidth	SLM		
Beam pointing stability 7)	< 50 µrad		
Typical beam diameter ⁸⁾	1.2 mm		
Optical jitter	< 0.2 ns ⁹⁾		
DIMENSIONS			
	160 005	50.5	

- ¹⁾ Due to continuous improvements all specifications are subject to change. Unless stated otherwise all specifications are measured at 1064 nm.
- ²⁾ FWHM level at 1064 nm. ³⁾ Averaged from 60 seconds time
- interval. 4) Over 8-hour period after max 5 minutes of warm-up when ambient temperature variation is less than ±2 °C.
- ⁵⁾ Factory-set pulse repetition rate is fixed at max repetition rate. Higher repetition rates are available, please inquire for details.
- ⁶⁾ Full angle measured at the 1/e² level.
- ⁷⁾ RMS value measured from 1000 shots.
- 8) Beam diameter is measured 20 cm from laser output at the $1/e^2$ level.
- 9) In respect to Q-switch triggering rising edge pulse.



Typical beam intensity profile (20 cm from laser output) of MPL15100 series lasers



MPL15100 laser head dimensions with attached harmonics unit (in mm)

	257 x 271 x 152 mm
	237 * 271 * 133 11111
Cable cord length	1 m

OPERATING REQUIREMENTS

Cooling requirements	air cooled		
Ambient temperature	15 – 30 °C		
Relative humidity	10 - 80 % (non-condensing)		
Mains voltage	100 – 240 VAC, single phase, 50 – 60 Hz		
Power consumption	< 10 W	< 100 W	

Diode Pumped Sub-Nanosecond Passively Q-Switched Laser MNL1342

FEATURES

- > More than **50 µJ** pulse energy at **1342 nm**
- Short pulse duration < 0.5 ns</p>
- > 1 100 Hz repetition rate
- Passively Q-switched
- > Average power 5 mW
- > Peak power 100 kW
- > Guaranteed > 3 Gshot lifetime
- Other wavelengths (e. g. 1342 nm, 671 nm, 447 nm) are available

MNL1342 series DPSS passively Q-switched sub-nanosecond lasers deliver high peak powers > 100 kW at 100 Hz repetition rate. Short laser cavity is fixed on thermostabilized and controlled baseplate which gives extremely stable output parameters performance. Small footprint is welcome point for integration into OEM lasers. Subnanosecond pulse duration of < 0.5 ns, high pulse energy more than 50 μ J, variable repetition rate from 1 Hz to 100 Hz covers many applications like pollution monitoring, DNA analysis, supercontinuum generation and many others.

Due to short pulse duration and high pulse energy laser delivers high peak power which is up to 100 kW. Optional conversion to green (532 nm) and ultraviolet (355 nm, 266 nm) is also available.

APPLICATIONS

- Laser-induced breakdown spectroscopy (LIBS)
- > Time resolved fluorescence measurements
- > DNA analysis
- > Pollution monitoring
- > Remote sensing
- > Supercontinuum generation
- > Ignition of gas mixtures





Specifications ¹⁾

MODEL	MNL1342		
Pulse energy:			
at 1342 nm	50 µJ		
at 671 nm	20 µJ		
at 447 nm	15 µJ		
at 336 nm	10 µJ		
Typical pulse duration	< 0,5 ns ²⁾		
Pulse to pulse energy stabilit	y (RMS):		
at 1342 nm	< 1.0 % ³⁾		
at 671 nm	< 2.5 % ³⁾		
at 447 nm	< 3.5 % ³⁾		
at 336 nm	< 5.0 % ³⁾		
Power drift	± 3.0 % ⁴⁾		
Pulse repetition rate ⁵⁾	100 Hz		
Beam profile	M ² < 1.5		
Beam divergence 6)	< 6 mrad		
Polarization	Linear, at 1342 nm		
Spectral linewidth	SLM		
Beam pointing stability 7)	< 40 µrad		
Typical beam diameter ⁸⁾	1.5 mm		
Optical jitter	~ 2 µs RMS ⁹⁾		

DIMENSIONS

Laser head (W×L×H)	121 × 295 × 140 mm
Controller unit (W×L×H)	115 × 195 × 60 mm

OPERATING REQUIREMENTS

Cooling requirements	air cooled	
Ambient temperature	15 – 30 °C	
Relative humidity	10 - 80 % (non-condensing)	
Mains voltage	100 – 240 VAC, single phase, 47 – 63 Hz ¹⁰⁾	
Power consumption	< 50 W	< 10 W





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- ¹⁾ Due to continuous improvements all specifications are subject to change. Unless stated otherwise all specifications are measured at 1342 nm.
- FWHM level at 1342 nm.
 Averaged from 60 seconds time
- interval in 5 series.
 Over 8-hour period after max 5 minutes of warm-up when ambient temperature variation is less than ±2 °C.
- Factory-set pulse repetition rate is fixed at 100 Hz repetition rate. Higher repetition rates are available, please inquire for more details.
- ⁶⁾ Full angle measured at the 1/e² level. Lower beam divergence is available upon request, please inquire for more details.
- 7) RMS value measured from 1000 shots.
- ⁸⁾ Beam diameter is measured 20 cm from laser output at the 1/e² level.
- ⁹⁾ In respect to Q-switch triggering rising edge pulse.
- ¹⁰⁾ Laser can be powered from appropriate 12 VDC power source. Inquire for details.





Typical beam intensity profile (20 cm from laser output) of MNL1342 series lasers



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